## Product Description

The PE4246 RF Switch is designed to cover a broad range of applications from 1 to 5000 MHz . It is non-reflective at both RF1 and RF2 ports. This SPST switch integrates a single-pin CMOS control interface, and provides low insertion loss while operating with extremely low bias from a single +3 -volt supply. In a typical application, the high isolation PE4246 can replace multiple RF switches of lesser isolation performance. It is offered in a small $3 x 3 \mathrm{~mm}$ DFN package.

The PE4246 is manufactured on Peregrine's UltraCMOS ${ }^{\text {TM }}$ process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Figure 1. Functional Diagram
Peregrine Specification 71/0008


CTRL

RF2


## Product Specification

## PE4246

## Absorptive SPST UltraCMOS ${ }^{\text {TM }}$ RF Switch: 1-5000 MHz

## Features

- Non-reflective 50 -ohm RF switch
- 50 -ohm ( 0.25 watt) terminations
- High isolation: 55 dB at 1000 MHz , 48 dB at 3000 MHz
- Low insertion loss. 0.8 dB at 1000 MHz , 0.9 dB ot 3000 MH
- High linearity +33 dB input 1 dB oompression point
- CMOS/TT single-pin control
- Single 3 -voltsupply operation
- Extremely How bias: $33 \mu \mathrm{~A} @ 3 \mathrm{~V}$

Availabie in a 6-lead DFN package
Figure 2. Package Type
6-lead DFN


Table 1. Electrical Specifications $@+25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}(\mathrm{ZS}=\mathrm{ZL}=50 \Omega)$

| Parameter | - Condition | Minimum | Typical | Maximum | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Operation Frequency ${ }^{1}$ | $\cdots$ - | 1 |  | 5000 | MHz |
| Operating Power | CTRL $=1 / \mathrm{CTRL}=0$ |  |  | 30/24 | dBm |
| Insertion Loss | $\begin{aligned} & 1-2000 \mathrm{MHz} \\ & 2000-3000 \mathrm{MHz} \\ & 3000-4000 \mathrm{MHz} \\ & 4000-5000 \mathrm{MHz} \end{aligned}$ |  | $\begin{aligned} & 0.8 \\ & 0.9 \\ & 1.0 \\ & 1.3 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.1 \\ & 1.3 \\ & 1.8 \end{aligned}$ | dB <br> dB <br> dB <br> dB |
| Isolation | $\begin{aligned} & 1-2000 \mathrm{MHz} \\ & 2000-3000 \mathrm{MHz} \\ & 3000-4000 \mathrm{MHz} \\ & 4000-5000 \mathrm{MHz} \end{aligned}$ | $\begin{aligned} & 49 \\ & 45 \\ & 43 \\ & 40 \end{aligned}$ | $\begin{aligned} & 55 \\ & 48 \\ & 46 \\ & 44 \end{aligned}$ |  | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ |
| Return Loss | $1-5000 \mathrm{MHz}$ | 11 | 20 |  | dB |
| Input 1 dB Compression ${ }^{3}$ | $1-5000 \mathrm{MHz}$ | 30 | 33 |  | dBm |
| Input IP3 | 1-5000 MHz | 50 |  |  | dBm |
| Video Feedthrough ${ }^{2}$ |  |  |  | 15 | $\mathrm{mV}_{\mathrm{pp}}$ |
| Switching Time |  |  | 2 |  | $\mu \mathrm{s}$ |

Notes: 1. Device linearity will begin to degrade below 1 MHz .
2. The DC transient at the output of the switch when the control voltage is switched from Low to High or High to Low in a $50 \Omega$ test set-up, measured with 1 ns risetime pulses and 500 MHz bandwidth.
3. Note Absolute Maximum ratings in Table 3.

Figure 3. Pin Configuration


Table 2. Pin Descriptions

| Pin No. | Pin Name | Description |
| :---: | :---: | :---: |
| 1 | $V_{D D}$ | Nominal 3 V supply connection. ${ }^{1}$ |
| 2 | GND | Ground connection. ${ }^{3}$ |
| 3 | RF1 | RF port. ${ }^{2}$ |
| 4 | CTRL | CMOS or TTL logic level: <br> High = RF1 to RF2 signal path <br> Low = RF1 isolated from RF2 |
| 5 | GND | Ground connection. ${ }^{3}$ |
| 6 | RF2 | RF port. ${ }^{2}$ |
| Notes: 1. A bypass capacitor should be placed as close as possible to the pin. <br> 2. Both RF pins must be DC blocked by an external capacitor or held at $0 \mathrm{~V}_{\mathrm{Dc}}$. <br> 3. The exposed pad must be soldered to the ground plane for proper switch performance. |  |  |

Table 3. Absolute Maximum Ratings

| Symbol | Parameter/Condition | Min | Max | Unit |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{DD}}$ | Power supply voltage | -0.3 | 4.0 | V |
| $\mathrm{~V}_{\mathrm{I}}$ | Voltage on CTRLLipput | -0.3 | 5.5 | V |
| $\mathrm{~T}_{\mathrm{ST}}$ | Storage temperature | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{P}_{\mathrm{IN}}$ | mput power $(50 \Omega)$, <br> CTRL-1/CTRL=0 |  | $33 / 24$ | dBm |
| $\mathrm{V}_{\text {ESD }}$ | ESD voltage <br> (Human Body Model) |  | 200 | V |

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

## Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the PE4246 in the 6 -lead $3 \times 3$ DFN package is MSL1.

## Device Description

The PE4246 high-isolation SPST RF Switch is designed to support a variety of applications where high isolation performance is demanded and a non-reflective input and output is desired. This switch is able to replace multiple lesser performing switches in a very small $3 \times 3 \mathrm{~mm}$ DFN footprint.

Table 4. Operating Rânges

| Parameter | Min |  | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $V_{\text {D }}$ Power Supply | 2.7 | 3.0 | 3.3 | V |
| IDD Power Supply Ourrent $\left(\mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}, \mathrm{~V}_{\mathrm{CNTL}}=3 \mathrm{~V}\right)$ |  | 33 | 40 | $\mu \mathrm{A}$ |
| $\mathrm{T}_{\mathrm{OP}}$ Operating temperature | -40 |  | 85 | ${ }^{\circ} \mathrm{C}$ |
| Control Voltage High | $0.7 \mathrm{x} \mathrm{V}_{\mathrm{DD}}$ |  | 5 | V |
| Control Voltag | 0 |  | $0.3 \times V_{\text {DD }}$ | V |

Table 5. Control Logic Truth Table

| Control Voltage | Signal Path |
| :---: | :---: |
| $C$ CTRL = CMOS or TTL High | RF1 to RF2 |
| CTRL = CMOS or TTL Low | RF1 isolated from RF2 |

## Control Logic

The control logic input pin (CTRL) is typically driven by a 3-volt CMOS logic level signal, and has a threshold of $50 \%$ of $\mathrm{V}_{\mathrm{DD}}$. For flexibility to support systems that have 5 -volt control logic drivers, the control logic input has been designed to handle a 5 -volt logic HIGH signal. (A minimal current will be sourced out of the $V_{D D}$ pin when the control logic input voltage level exceeds $\mathrm{V}_{\mathrm{DD}}$.)

## Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS ${ }^{\text {TM }}$ device, observe the same precautions that you would use with other ESDsensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 3.

## Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS ${ }^{\text {TM }}$ devices are immune to latch-up.

## Typical Performance Data @ $25^{\circ} \mathrm{C}$ (Unless Otherwise Noted)

Figure 4. Insertion Loss
$\mathrm{T}=-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$


Figure 5. Input 1dB Compression Point and IIP3


Figure 6. Isolation


## Typical Performance Data @ +25 ${ }^{\circ} \mathrm{C}$

Figure 7. RF1 Return Loss $(C T R L=$ High $)$


Figure 9. RF1 Return Loss (CTRL = Low)


Figure 8. RF2 Return Loss (CTRL = High)


Figure 10. RF2 Return Loss (CTRL = Low)


## Evaluation Kit

The SPST Switch Evaluation Kit board was designed to ease customer evaluation of the PE4246 SPST switch. The RF1 port is connected through a $50 \Omega$ transmission line to the top left SMA connector, J1. The RF2 port is connected through a $50 \Omega$ transmission line to the top right SMA connector, J2. A through transmission line connects SMA connectors J3 and J4. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031 ". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide model with trace width of 0.0476 ", trace gaps of 0.030 ", dielectric thickness of 0.028 ", metal thickness of 0.0021 " and $\varepsilon R$ of 4.3. Note that the predominate mode for these transmission lines is coplanar waveguide with a ground plane.

J5 and J6 provide a means for controlling DC and digital inputs to the device. J6-1 is connected to the device $\mathrm{V}_{\mathrm{DD}}$ input. $\mathrm{J} 5-1$ is connected to the device CTRL input. J5-2 and J6-2 are GND connections. A decoupling capacitor ( 100 pF ) is provided on both CTRL and vo traces. It is the responsibility of the customer to determine proper supply decoupling for their design application. Removing these components trom the evaluation board has not been shown to degrade RF performance


Figure 11. Evaluation Board Layouts
Peregrine Specification 101/0102


Figure 12. Evaluation Board Schematic
Peregrine Specification 102/0134


Figure 13. Package Drawing

6 -lead DFN



NOTE: The exposed solder pad (Onthe bottom of the package) is not electrically connected to any other pin (isolated).

Figure 14. Marking Specification


YYWW = Date Code (last two digits of year and work week)
ZZZZZ = Last five digits of Lot Number

Figure 15. Tape and Reel Specifications
6 -lead DFN


Table 6. Dimensions

| Dimension | DFN 3x3 mm |
| :---: | :---: |
| Ao | $3.23 \pm 0.1$ |
| Bo | $3.17 \pm 0.1$ |
| Ko | $1.37 \pm 0.1$ |
| P | $4 \pm 0.1$ |
| W | $8+0.3 .-0.1$ |
| T | $0.254 \pm 0.02$ |
| R7 Quantity | 3000 |
| R13 Quantity | N.A. |



Device Orientation in Tape

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## Table 7. Ordering Information

| Order Code | Part Marking | Description | Package | Shipping Method |
| :---: | :---: | :---: | :---: | :---: |
| $4246-51$ | 4246 | PE4246G-06DFN 3x3mm-12800F | Green 6-lead 3×3 mm DFN | Tape or loose |
| $4246-52$ | 4246 | PE4246G-06DFN 3x3mm-3000C | Green 6-lead 3x3 mm DFN | 3000 units $/$ T\&R |
| $4246-00$ | PE4246-EK | PE4246-06DFN 3x3mm-EK | Evaluation Kit | $1 /$ Box |

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## Data Sheet Identification

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The product is in a formative or designs stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

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The data sheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

## Product Specification

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